



Rev.02 - 23 December 2019

Product data sheet

1. General description

Planar passivated very sensitive gate four quadrant triac in a TO92 plastic package. This very sensitive gate "series D" triac is intended for interfacing with low power drivers including microcontrollers.

2. Features and benefits

- Direct interfacing to logic level ICs
- · Direct interfacing with low power gate drivers and microcontrollers
- High blocking voltage capability
- · Planar passivated for voltage ruggedness and reliability
- · Very sensitive gate
- Triggering in all four quadrants

3. Applications

- Air conditioner indoor fan control
- General purpose low power motor control
- · General purpose switching and phase control

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Absolute	maximum rating					
V_{DRM}	repetitive peak off-state voltage		-	-	600	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T _{lead} ≤ 51 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	-	-	1	A
I _{TSM} non-repetitive peak on- state current		full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	-	13.7	А
T _j	junction temperature		-	-	125	°C
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
I _{GT}	gate trigger current	V_{D} = 12 V; I _T = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V _D = 12 V; I _T = 0.1 A; T2- G-; T _i = 25 °C; <u>Fig. 7</u>	-	-	5	mA

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		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	-	-	7	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.3	10	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic	characteristics					
$ dV_{\text{D}}/dt \ \ \text{rate of rise of off-state} \ \ V_{\text{DM}} = 402 \text{ V}; \text{T}_{\text{j}} = 125 ^{\circ}\text{C}; (\text{V}_{\text{DM}} = 67\% \text{of } \text{V}_{\text{DRM}}); \text{ exponential waveform}; \\ \text{R}_{\text{GT1(ext)}} = 1 \text{k}\Omega $		20	-	-	V/µs	
dV _{com} /dt	rate of change of commutating voltage	$V_D = 400 \text{ V}; \text{T}_\text{j} = 125 \text{ °C}; \text{dI}_\text{com}/\text{dt} = 0.5 \text{ A/ms};$ $\text{I}_T = 1 \text{ A}; \text{ gate open circuit}$	3	-	-	V/µs

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	T2	main terminal 2		
2	G	gate		T2-T1
3	T1	main terminal 1) TO-92 (SOT54)	sym051

6. Ordering information

Table 3. Ordering information								
Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
BT131-600D	TO92	BT131-600D,412	Bulk	1000	SOT54	14-Nov-2013		
BT131-600D	TO92	BT131-600DQP	Reel	2000	SOT54	14-Nov-2013		
BT131-600D/L01	TO92	BT131-600D/L01EP	Bulk	500	SOT54/L01	14-Nov-2013		

7. Marking

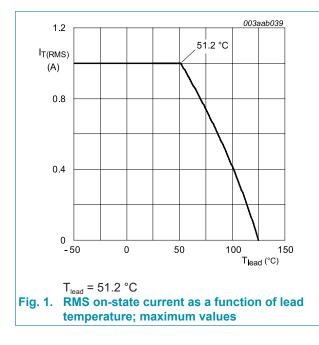
Table 4. Marking codes						
Type number	Marking codes					
BT131-600D	131-6D					

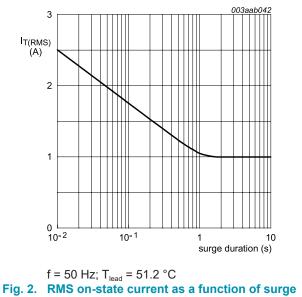
8. Limiting values

Table 5. Limiting values

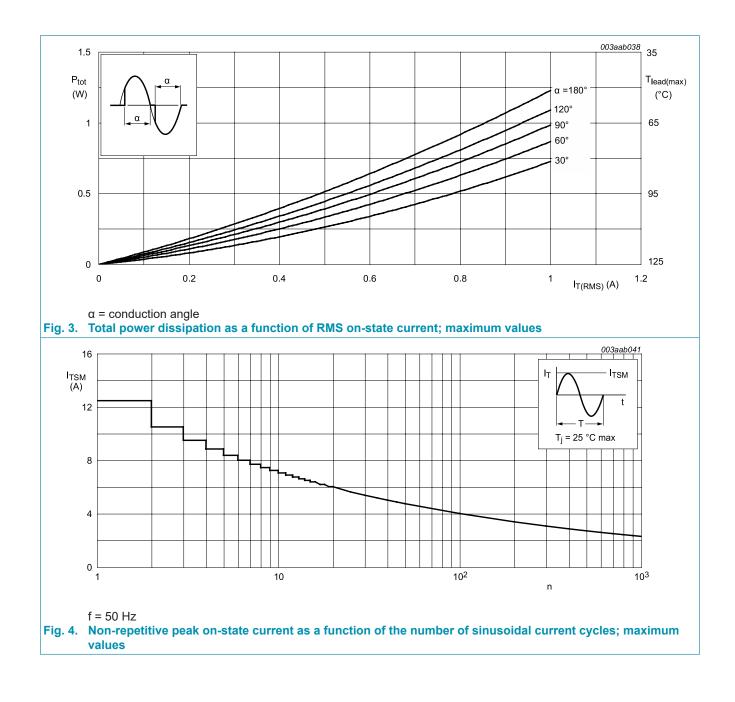
In accordance with the Absolute Maximum Rating System (IEC 60134).

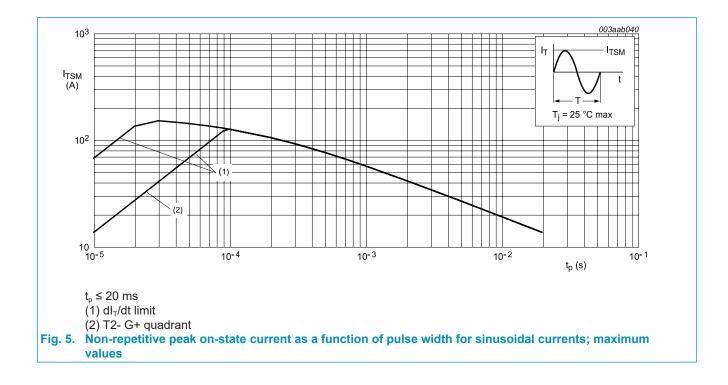
Symbol	Parameter	Conditions	Min	Max	Unit
V_{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state currentfull sine wave; $T_{lead} \le 51 \degree C$; Fig 1; Fig 2;Fig 3		-	1	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig 4; Fig 5	-	12.5	A
		full sine wave; $T_{j(init)}$ = 25 °C; t_p = 16.7 ms	-	13.7	А
l ² t	I ² t for fusing	t _P = 10 ms; SIN	-	0.78	A ² s
dl _⊤ /dt	rate of rise of on-state	I _G = 10 mA	-	50	A/µs
	current	I _G = 10 mA	-	50	A/µs
		I _G = 14 mA	-	10	A/µs
		I _G = 10 mA	-	50	A/µs
I _{GM}	peak gate current		-	2	Α
P_{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C





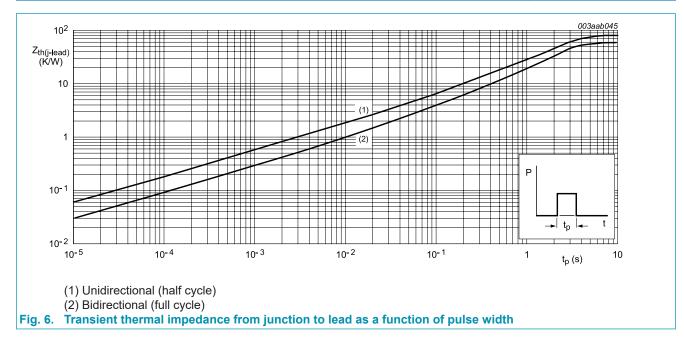
duration; maximum values





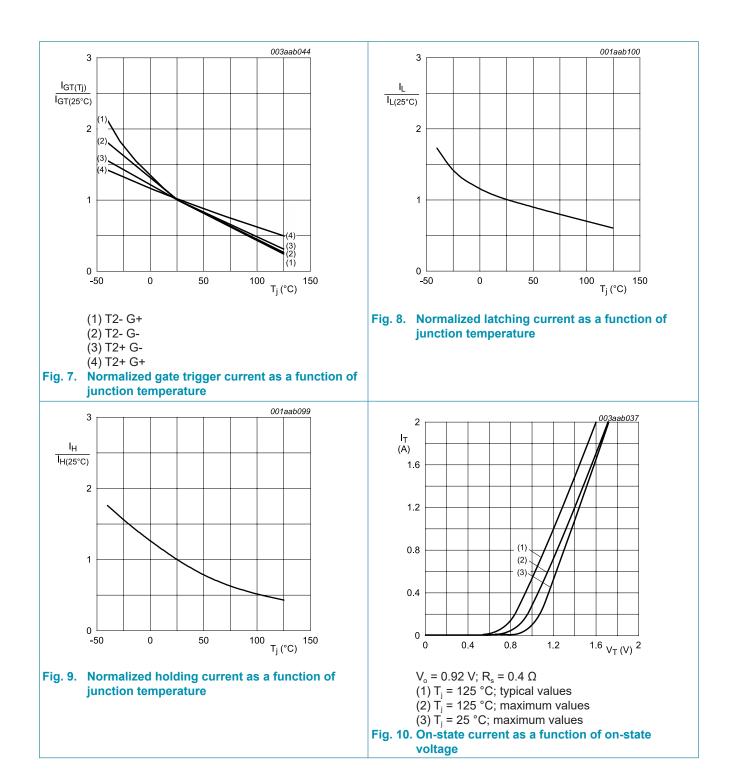
9. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance	full cycle; <u>Fig 6</u>	-	-	60	K/W
	from junction to lead	half cycle; <u>Fig 6</u>	-	-	80	K/W
$R_{th(j\text{-}a)}$	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



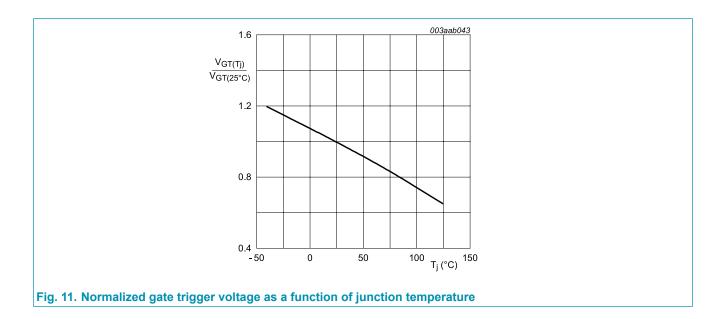
10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	aracteristics	1				
I _{GT}	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	5	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	5	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 7</u>	-	-	5	mA
		V_{D} = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; Fig. 7	-	-	7	mA
IL	latching current	$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	10	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2+ G-};$ T _j = 25 °C; Fig. 8	-	-	20	mA
		$V_D = 12 \text{ V}; \text{ I}_G = 0.1 \text{ A}; \text{ T2- G-};$ T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		$V_D = 12 \text{ V}; I_G = 0.1 \text{ A}; \text{ T2- G+};$ T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	1.3	10	mA
V _T	on-state voltage	I _T = 1.4 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	$V_D = 12 \text{ V}; I_T = 0.1 \text{ A}; T_j = 25 \text{ °C};$ Fig. 11	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 125 °C	0.2	0.3	-	V
I _D	off-state current	V _D = 600 V; T _j = 125 °C	-	0.1	0.5	mA
Dynamic	characteristics	· · · · ·				
dV _D /dt	rate of rise of off-state voltage		20	-	-	V/µs
dV _{com} /dt	rate of change of commutating voltage $V_D = 400 V; T_j = 125 °C; dI_{com}/dt = 0.5 A$ ms; $I_T = 1 A;$ gate open circuit		3	-	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 1.5 A; V_D = 600 V; I_G = 0.1 A; dI_G/dt = 5 A/µs	-	2	-	μs

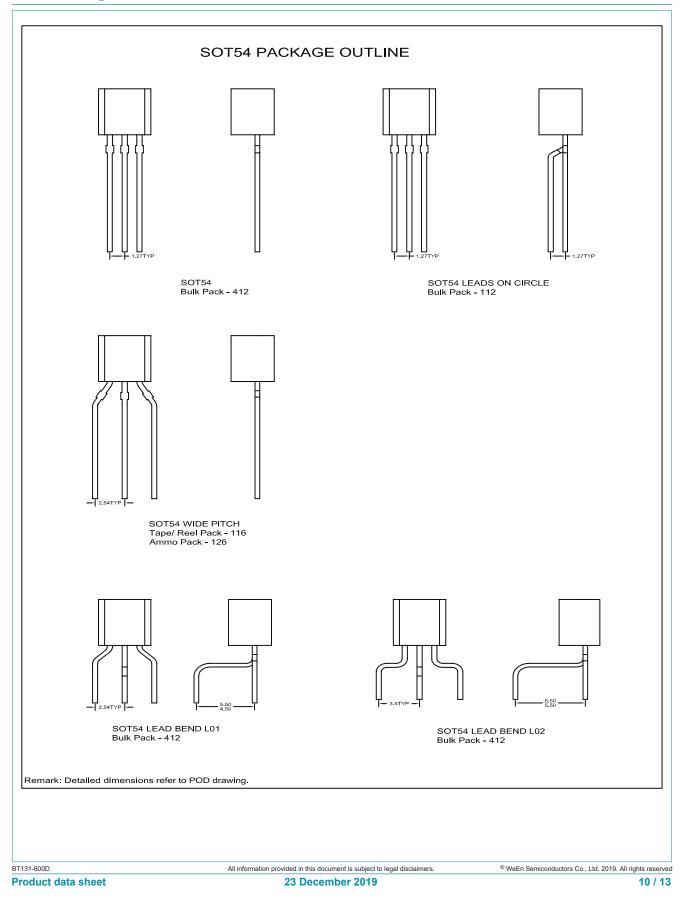


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11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

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